Supporting Information

Towards enhanced sodium storage of anatase TiO₂ via a dual-modification approach of Mo doping combined with AlF₃ coating

Xue Bai, bc Tao Li,*cd Umair Gulzar, cd Eleonora Venezia, c Lin Chen, c Simone Monaco, c Zhiya Dang, c

Mirko Prato,^c Sergio Marras,^c Pejman Salimi Naden,^c Silvio Fugattini,^c Claudio Capiglia^e and Remo

Proietti Zaccaria*ac

^a Cixi Institute of Biomedical Engineering, Ningbo Institute of Materials Technology and

Engineering, Chinese Academy of Sciences, Ningbo 315201, China

^b College of Materials Science and Engineering, Shandong University of Science and Technology, Qingdao 266590, China

^c Istituto Italiano di Tecnologia, via Morego 30, Genova 16163, Italy

^d DIBRIS, University of Genova, via Opera Pia 13, Genova 16145, Italy

^e Nagoya Institute of Technology, Gokiso-cho, Showa-ku, Nagoya, Aichi, 466-8555, Japan

*Corresponding author. E-mail: Tao.Li@iit.it, Remo.Proietti@iit.it, Remo.Proietti@nimte.ac.cn

Table S1 Calculated lattice parameters *a*, *c* and crystalline size of the as-prepared TO and MTO samples. The whole powder pattern decomposition (WPPD) analysis, based on Pawley method, was carried out to determine the cell parameters, average size of the crystalline domains and strain of both the undoped and doped samples. Instrumental broadening was calculated using a NIST SRM 660c LaB6 powder.

	<i>a=b</i> (Å)	<i>c</i> (Å)	Crystalline size (nm)	Strain (%)
TO (pure TiO ₂)	3.7867	9.5051	20.0	0.294
MTO (5% doped)	3.7878	9.4946	16.2	0.342



Fig. S1 XPS of MTO and MTO@AlF₃ before cycling (left) and after cycling (right).

Fig. S1 left shows the comparison of Ti 2p and Mo 3d spectra collected on the MTO and the MTO@AlF₃ samples before cycling. XPS data suggest that the procedure used for realizing the AlF3

coating on the surface of the MTO particles did not affect the oxidation states of neither Ti nor Mo. Indeed, in both samples, the Ti 2p spectrum is characterized by the Ti $2p_{3/2}$ and Ti $2p_{1/2}$ peaks located at (458.7±0.2) eV and (464.4±0.2) eV, typical of Ti(IV) oxide [1]. For both cases, Mo 3d spectra could be fitted by a couple of doublets; the most intense doublet, with Mo $3d_{5/2}$ and Mo $3d_{3/2}$ peaks at (232.6±0.2) eV and (235.7±0.2) eV, is indicative of Mo(VI) species [2], while the less intense one, with Mo $3d_{5/2}$ and Mo $3d_{3/2}$ peaks at (231.6±0.2) eV and (234.7±0.2) eV, could be attributed to Mo(V) species [3]. The main difference between the two samples is the [Mo(V)]/[Mo(VI)] ratio, equal to 0.3 and to0.2 for the MTO and MTO@AlF₃ samples, respectively. Finally, it is observed that the presence of surface fluorides could have induced a higher oxidation of Mo in MTO@AlF₃.

When it comes to MTO@AlF₃ after cycling, the results are summarized in Fig. S1 right. The figure shows the comparison of Ti 2p and Mo 3d spectra collected on the MTO and the MTO@AlF₃ samples, after cycling. Also in this case, XPS data indicate that the oxidation states of Ti and Mo in the two samples are similar, even after their use in Na-ion batteries, as the Ti 2p and Mo 3d spectra are almost the same.

In both samples, the Ti 2p spectrum is characterized by the Ti $2p_{3/2}$ and Ti $2p_{1/2}$ peaks located at (459.8±0.2) eV and (465.5±0.2) eV. The positions are approx. 1 eV higher than those measured on the starting materials, most likely because of the presence of a high concentration of fluorine in the sample (due to the PVDF binder used in the preparation of the electrodes). With this in mind, we assigned the observed peaks to Ti(IV) oxide. For both samples, the best fit of the Ti 2p spectra was obtained by adding also a second doublet of peaks, with Ti $2p_{3/2}$ and Ti $2p_{1/2}$ peaks located at (458.3±0.2) eV and (464.0±0.2) eV, i.e., at approx. 1.5 eV below the Ti(IV) peaks. We therefore assigned this minor intensity doublet to Ti(III) species [1].

Mo 3d spectrum in both cases is dominated by a doublet with Mo $3d_{5/2}$ and Mo $3d_{3/2}$ peaks at (233.9±0.2) eV and (237.0±0.2) eV, that we assigned to Mo(VI) species, even if shifted to higher energies with respect to what measured on the starting materials. Again, we assign the shift to the electron-withdrawal effect due to the presence of high amounts of highly electronegative fluorine species from PVDF. To obtain the best fit, we had to add in both cases also other four peaks, which could be assigned to Mo(IV) species, according to [4].

With respect to the before cycling materials, it is interesting to notice that both Ti and Mo show the presence of reduced species (i.e., Ti(III) and Mo(IV)), likely due to a partial residue of Na⁺ in the

material after "sodiation", inducing therefore Ti and Mo reduction in order to maintain charge neutrality in the system.

Finally, when looking at the effect of AlF₃ on SEI formation, XPS data (not shown here) depict a higher presence of C-related components in case of absence of AlF₃. This result suggests that AlF₃ might mitigate the SEI formation with an overall positive influence on the cell. However, a detailed and dedicated study in this direction would be necessary before reaching any clear conclusion as the binder contribution to the C-related peaks could change from sample to sample. In this respect, it should be setup a standardization for the washing procedure in order to guarantee a proper reading and interpretation of the C-peaks in the XPS analysis.



Fig. S2 (a, b) SEM images of TO and the corresponding EDS elemental mappings of (d) O and (e) Ti, referred to image (c).



Fig. S3 (a, b) SEM images of MTO and the corresponding EDS elemental mappings of (d) O and (e) Ti and (f) Mo, referred to image (c).



Fig. S4 TEM images of (a, d) TO, (b, e) MTO, and (c, f) MTO@AlF₃.



Fig. S5 XRD pattern of the MTO@AlF₃ sample (with AlF₃ content of 1wt%).



Fig. S6 (a) Galvanostatic discharge–charge voltage curves for the 2^{nd} cycle at 0.1 C between 0.01 and 2.5 V, (b) the corresponding differential capacity (dQ/dV) *vs.* voltage plots of TO, MTO, and MTO@AlF₃.



Fig. S7 Cycling performance of 3wt%-AlF₃ coated MTO sample at 0.1C.

Table S2 Brief summary of electrochemical performance for modified TiO_2 anodes via various preparation methods.

Materials	Preparation		Capacity/Current	Capacity at high	Ref.
	methods		density	rate	
			$(mAh g^{-1}/mA g^{-1})$	$(mAh g^{-1}/mA g^{-1})$	
Nb-doped TiO ₂	sol-gel		177/33	108.8/1650	[S1]
nanoparticles			(100 cycles)		
Sn-doped TiO ₂	sol-gel	and	257/50	106/5000	[S2]

nanotubes	subsequent	(50 cycles)		
	hydrothermal			
Fe-doped TiO ₂ /	wet chemistry	304/100	198/2000	[S3]
amorphous carbon	process	(50 cycles)		
composite				
Mo-doped TiO ₂	sol-gel	231.8/33.5	108.3/1680	[S4]
nanoparticles		(100 cycles)		
Co-doped TiO ₂	solvothermal	170/100	121/1000	[S5]
nanodisks		(100 cycles)		
N-doped TiO ₂	hydrothermal and	166/840	131/3360	[S6]
nanorods	ionic exchange	(300 cycles)		
B-doped TiO ₂	sol-gel	225/33	147/660	[S7]
nanoparticles		(5 cycles)		
Carbon coated anatase	hydrothermal	201.3/168	90/3360	[S8]
TiO ₂ mesocrystals		(500 cycles)		
N and S co-doped	hydrothermal	193.8/100	120.9/1000	[S9]
hollow CNF/S-doped		(50 cycles)		
anatase TiO ₂				
Mo-doped TiO ₂ @AlF ₃	co-precipitation	178.9/33.5	98.4/1675	This
		(50 cycles)		work



Fig. S8 (a) Galvanostatic charge-discharge voltage curves for the initial cycle of

MTO@AlF₃|NaNMO full cell between 0.1 and 4.1 V at specific current of 20 mA g^{-1} , (b) the rate performance of MTO@AlF₃|NaNMO full cell at different specific current of 20, 40, 60, 100, 200, 500, 1000 mA g^{-1} and eventually come back to 20 mA g^{-1} . The specific capacity is based on the reference of MTO@AlF₃.

Na-ion full cell assembling:

In order to validate MTO@AIF₃ anode material in Na-ion full cell, lab-made P2-type Na_{2/3}Ni_{1/4}Mn_{3/4}O₂ (NaNMO) was used as the cathode material to match with MTO@AlF₃ anode. The positive electrode was prepared by casting the mixed slurry of NaNMO nanoparticles (85 wt.%), super P carbon (10 wt.%), and polyvinylidene fluoride (5 wt.%) in N-methylpyrrolidone onto etched aluminum foil. The coating was calendered and further dried at 120 °C under vacuum for at least 2 hours before use. The balance calculation of the full cell was calculated based on the capacity ratio of QAnode: QCathode as 1.10. Accordingly, we designed the Na full cell by adjusting the mass loading of active material at negative and positive electrodes to 1:1.5. CR2032-type coin cells with NaNMO and MTO@AIF₃ as cathode and anode respectively, were assembled and sealed in the glovebox (H₂O and $O_2 < 0.1$ ppm). 1.0 M of NaClO₄ in a mixture solvent of ethylene carbonate and propylene carbonate (1:1 by volume) was used as electrolyte, and glass filter (Whatman) was used as separator. It is noted that before the full cell assembly, negative electrode (electrode preparation process is given in Section 2.3 in the main text) was firstly cycled at 0.1C (33.5 mA g⁻¹) for two cycles to ensure a high reversibility of MTO@AIF₃ in a Na half-cell with a sodium metal disc used as counter and reference electrode. Then the cycled half-cell was disassembled in the glovebox and the working electrode was taken out for the subsequent full cell assembly. MTO@AlF3|NaNMO full cell was charged/discharged using a constant current protocol in the voltage range of 0.1-4.1 V at different specific current of 20, 40, 60, 100, 200, 500, 1000 mA g^{-1} and eventually come back to 20 mA g^{-1} . All the measurements were done at room temperature. The electrochemical performance of the full cell is shown in Fig. S8. Interestingly, even though the initial cycle shows a strong irreversibility (Fig. S8a), it appears that the cell undergoes a kind of recovery upon cycling as emerging from Fig. S8b. The full cell delivers a discharge capacity of 139.9 mAh g⁻¹ based on the reference of MTO@AlF₃ at a current density of 20 mA g⁻¹ (Fig. S8a) and good rate capabilities (Fig. S8b), demonstrating its promising potential for energy storage systems.

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